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Phys. Rev. B **94**, 085129 — Published 16 August 2016

DOI: [10.1103/PhysRevB.94.085129](https://doi.org/10.1103/PhysRevB.94.085129)

The number of holes contained within the Fermi surface volume in underdoped high temperature superconductors

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(Dated: July 25, 2016)

We provide a potential solution to the longstanding problem relating Fermi surface reconstruction to the number of holes contained within the Fermi surface volume in underdoped high T_c superconductors. On considering uniaxial and biaxial charge-density wave order, we show that there exists a relationship between the ordering wave vector, the hole doping and the cross-sectional area of the reconstructed Fermi surface whose precise form depends on the volume of the starting Fermi surface. We consider a ‘large’ starting Fermi surface comprising $1 + p$ hole carriers, as predicted by band structure calculations, and a ‘small’ starting Fermi surface comprising p hole carriers, as proposed in models in which the Coulomb repulsion remains the dominant energy. Using the reconstructed Fermi surface cross-sectional area obtained in quantum oscillation experiments in $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ and $\text{HgBa}_2\text{CuO}_{4+x}$ and the established methods for estimating the chemical hole doping, we find the ordering vectors obtained from x-ray scattering measurements to show a close correspondence with those expected for the small starting Fermi surface. We therefore show the quantum oscillation frequency and charge-density wave vectors provide accurate estimates for the number of holes contributing to the Fermi surface volume in the pseudogap regime.

PACS numbers: 71.45.Lr, 74.72.-h, 74.72.Gh, 74.72.Kf

I. INTRODUCTION

The pseudogap is central to our understanding of high temperature superconductivity in the cuprates,^{1–3} yet the number of hole carriers contained within the Fermi surface volume has remained challenging to ascertain experimentally. At issue is the degree to which Coulomb interactions cause the pseudogap to depart from a conventional metallic state. In the case of a conventional metal, a ‘large’ Fermi surface volume consistent with band structure calculations is expected to result when Coulomb interactions between carriers are screened. In the cuprates, this large Fermi surface comprises $n_h = 1 + p$ hole carriers (see Fig. 1a),⁴ where, by convention, p is the hole doping defined relative to the half filled band. In the case of a more unconventional metal, by contrast, the on-site Coulomb repulsion is largely unscreened causing it to dominate over low energy excitations. In this case, antiferromagnetic correlations are expected to remove one hole per CuO_2 plane per unit cell, leading to a ‘small’ Fermi surface comprising $n_h = p$ hole carriers.^{5–8} One of the possible outcomes is a small Fermi surface consisting of four hole pockets located at the antiferromagnetic Brillouin zone boundary (see Fig. 1b).

The large and small Fermi surface volumes have both been reported in the experiments, but at opposite ends of the doping phase diagram and outside of the pseudogap regime (see Fig. 1c). Deep in the overdoped regime at hole dopings $p \gtrsim 0.20$, Hall effect,⁹ magnetic quantum oscillation¹⁰ and angle-dependent magnetoresistance oscillation⁵² measurements are all found to be consistent with the large Fermi surface. Deep in the underdoped regime at very low hole dopings, $p \lesssim 0.08$, meanwhile, Hall effect measurements¹² are found to be consistent with the small Fermi surface. The presence of some form

of spin order at these same very low dopings with a wave vector close to $\mathbf{Q} = (\pi, \pi)$ ^{54,55} suggests that the small Fermi surface there is the product of antiferromagnetism.

The pseudogap regime, for which the total volume of the Fermi surface has remained undetermined,¹³ spans a broad intermediate range of hole dopings $0.08 \lesssim p \lesssim 0.20$ (see Fig. 1c). The low temperature Hall effect has been found to be negative over much of this range in the highest quality samples,^{14,15} indicating it no longer to provide a direct measure of the number of holes contributing to the Fermi surface. X-ray scattering and nuclear magnetic resonance experiments have further revealed the presence of charge-density waves over most of this range rather than antiferromagnetism,^{16–23} with a possible broken rotational symmetry.

A biaxial charge-density wave order with two concurrent orthogonal wave vectors, $\mathbf{Q}_a = (\delta_a, 0)\frac{2\pi}{a}$ and $\mathbf{Q}_b = (0, \delta_b)\frac{2\pi}{b}$, has been shown account for a large body of experimental data relating to the reconstructed Fermi surface within the pseudogap regime.^{24–32} This data includes the small Fermi surface cross-sectional area found in quantum oscillation experiments,^{33–36} the negative value of the Hall coefficient at high magnetic fields^{14,15} and the small value of the electronic heat capacity at high magnetic fields.^{37,38} It has continued to remain unclear, however, as to whether it is a large starting Fermi surface (like that in Fig. 1a) or a small starting Fermi surface (similar to that in Fig. 1b) that becomes reconstructed by the charge-density wave.^{16–18,24–32,39,40}

Here we show that the observed reconstructed Fermi surface consisting mostly of a single electron pocket per CuO_2 plane^{30,41,42} and the measured values of the charge-density wave vectors^{17–21} together point conclusively to a small starting Fermi surface (see Fig. 1c). We show using geometry that there exists a simple expression

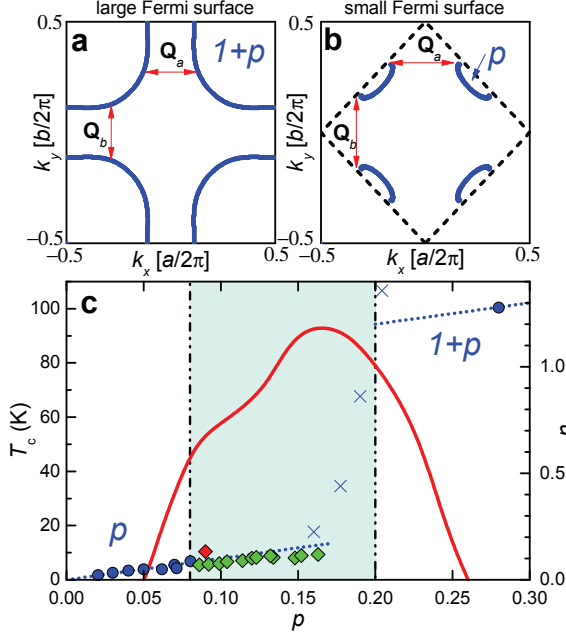


FIG. 1: (a), A schematic of the unreconstructed large cuprate hole Fermi surface⁴ (neglecting bilayer coupling) that contains $1+p$ holes per unit cell. \mathbf{Q}_a and \mathbf{Q}_b illustrate notional charge-density wave ordering vectors. (b), A schematic of a small Fermi surface, in which four small hole pockets bounded by the antiferromagnetic Brillouin zone boundary (dotted line) together contain p holes per unit cell. (c, left-hand axis) Notional doping-dependence of T_c (red curve).⁴⁸ The Fermi surface volume of the intermediate doping range (shaded in cyan) has not previously been ascertained. (c, right-hand axis) Experimental estimate of the number of holes, $n_h = 2A_{p,1+p}/A_{UBZ}$, contributing to the Fermi surface volume. Green and red diamonds indicate n_h estimated from the quantum oscillation frequency and charge-density wave vectors using Equation (4) in $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ and $\text{HgBa}_2\text{CuO}_{4+x}$, respectively. For $p < 0.1$, we assume $\delta_a = \delta_b$. Blue circles indicate the results of earlier Hall effect, angle-dependent magnetoresistance and quantum oscillation measurements,^{10,12,52} while crosses indicate the recent Hall results of Badoux *et al.*⁹ The dotted line represents $n_h = p$ (for $p < 0.2$) and $n_h = 1 + p$ (for $p \geq 0.2$) expected for a small and large Fermi surface, respectively.

for the dependence of the length of ordering vector $\delta_{a,b}$ on hole doping p and the momentum-space cross-sectional area of the reconstructed pocket(s) A_e . Here, δ_a and δ_b are defined relative to the lengths of the unreconstructed Brillouin zone reciprocal lattice vectors $\mathbf{K}_a = (\frac{2\pi}{a}, 0)$ and $\mathbf{K}_b = (0, \frac{2\pi}{b})$. The functional form of $\delta_{a,b}$ on p and A_e is sufficiently different for a large and small starting Fermi surface, that it can unambiguously distinguish between these scenarios. We therefore find A_e and $\delta_{a,b}$ to provide a reliable experimental means for estimating n_h over the majority of the pseudogap regime (see green and red diamonds in Fig. 1c).

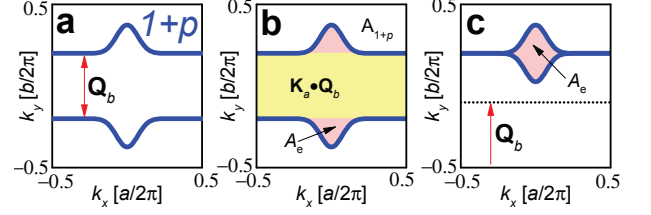


FIG. 2: (a), Schematic quasi-one-dimensional open Fermi surface (blue lines), with the charge-density wave ordering vector \mathbf{Q}_b indicated (red). (b), The same Fermi surface with the different area contributions shaded as described in the text. (c), Schematic reconstructed electron pocket after translation of part of the unreconstructed Fermi surface.

II. DERIVATION

The geometrical origin of the dependence of $\delta_{a,b}$ on p and A_e can be visualized by considering an idealized form for the unreconstructed Fermi surface, such as that expected to apply in $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ (shown in Fig. 1) when bilayer coupling and higher order hopping terms are neglected. Below we show that the derived expression for $\delta_{a,b}$ as a function of p and A_e remains robust against an increase in strength of the charge-density wave order. We also show it to remain robust against the introduction of bilayer hopping terms and changes in Fermi surface shape.

A. Open Fermi surface and uniaxial order

It is instructive to begin by considering the case of an open Fermi surface that becomes reconstructed by a unidirectional density-wave ordering vector (see Fig. 2a). An imperfectly nested unreconstructed Fermi surface of equivalent topology occurs in quasi-one-dimensional organic conductors,⁴³ and has also been proposed to occur in the cuprates when a large nematic distortion precedes the formation of a charge-density wave.⁴⁴ We assume that the charge-density wave ordering vector $\mathbf{Q}_b = (0, \delta_b) \frac{2\pi}{b}$ spans the flat portions of the Fermi surface sheets in Fig. 2a and that the carriers contained in the center of the Brillouin zone between the quasi-one-dimensional sheets are electrons.

As shown in Fig. 2b, the effect of the density-wave is to remove electrons from the unreconstructed Fermi surface that occupy an area equal to $\mathbf{K}_a \cdot \mathbf{Q}_b$ (indicated in yellow). After reconstruction, these electrons are accommodated within a series of completely filled reconstructed bands that lie below the chemical potential in the reconstructed electronic structure. On defining an irreducible rational fraction of the form $\delta_b = \frac{m_b}{n_b}$ for the ordering vector length, in which m_b and n_b are integers, a single band unreconstructed electronic structure is transformed into a reconstructed electronic structure consisting of $m_b n_b$ electronic bands. The electrons removed from the Fermi

surface are then contained within m_b completely filled bands that lie below the conduction band.

From visual inspection of Fig. 2b, we see that the area $\mathbf{K}_a \cdot \mathbf{Q}_b$ (indicated in yellow), the total area A_e of the unnested portion of the electron Fermi surface (indicated in pink) and the area $A_{1+p} = \frac{1}{2}(1+p)A_{UBZ}$ of the Brillouin zone occupied by holes (indicated in white) must together equal the area of the unreconstructed Brillouin zone $A_{UBZ} = \mathbf{K}_a \cdot \mathbf{K}_b$. Putting these terms together, we arrive at

$$\mathbf{K}_a \cdot \mathbf{Q}_b + A_e + A_{1+p} = A_{UBZ}$$

from which we obtain

$$\delta_b^{\text{open}} = \frac{1}{2}(1-p) - \frac{A_e}{A_{UBZ}} \quad (1)$$

upon substituting \mathbf{Q}_b and rearranging terms. The two unnested portions of the open Fermi surface in Fig. 2b (indicated in pink) come together in Fig. 2c to form a reconstructed Fermi surface consisting of a single electron pocket of area A_e (again, indicated in pink). The flat nested portions of the Fermi surface on either side of the reconstructed electron pocket in Fig. 2c will disappear from the reconstructed Fermi surface upon the introduction of coupling terms linking the open sheets in the charge-density wave Hamiltonian. For $p = 0$, the dependence of δ_b^{open} on A_e is the same as that obtained in the quantized nesting model of magnetic field-induced spin-density waves.⁴³

B. Large Fermi surface and biaxial order

On considering biaxial density-wave ordering starting from a large Fermi surface of the form shown in Fig. 1a, two ordering vectors \mathbf{Q}_a and \mathbf{Q}_b must now act in concert to remove electrons from the unreconstructed Fermi surface in Fig. 3a (indicated in yellow and green). We consider each of these in turn – the precise order being unimportant. Starting with \mathbf{Q}_b , its effect is again to remove electrons from the unreconstructed Fermi surface occupying a total area $\mathbf{K}_a \cdot \mathbf{Q}_b$ (indicated in yellow). The green and pink regions occupied by electrons survive this first step, but are folded by \mathbf{Q}_b to produce multiple Fermi surfaces in higher order Brillouin zones (not shown for clarity). The effect of the second ordering vector \mathbf{Q}_a is to remove remaining electrons from the unreconstructed Fermi surface occupying a total area $\mathbf{Q}_a(\mathbf{K}_b - \mathbf{Q}_b)$ (indicated in green). Defining $\delta_a = \frac{m_a}{n_a}$ and $\delta_b = \frac{m_b}{n_b}$, the reconstructed electronic structure consists of a total of $m_a m_b n_a n_b$ reconstructed bands. The electrons removed from the unreconstructed Fermi surface will then be contained within $m_a m_b (n_a + n_b - 1)$ completely filled bands that lie below the conduction band of the reconstructed band structure.

Again, on equating all of these areas to A_{UBZ} in Fig. 3a we arrive at

$$\mathbf{K}_a \cdot \mathbf{Q}_b + \mathbf{Q}_a(\mathbf{K}_b - \mathbf{Q}_b) + A_e + A_{1+p} = A_{UBZ}$$

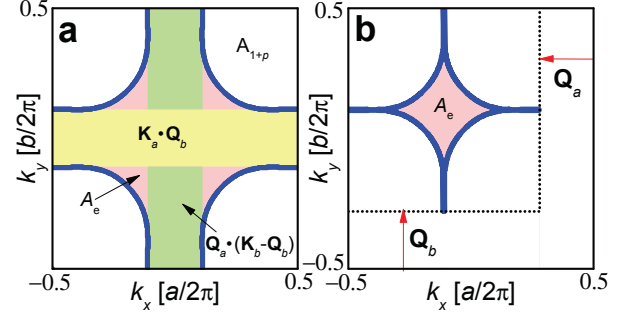


FIG. 3: (a), The large Fermi surface with the different area contributions shaded. (b), Schematic showing the reconstructed electron pocket after translation of parts of the unreconstructed Fermi surface by \mathbf{Q}_a , \mathbf{Q}_b and $\mathbf{Q}_a + \mathbf{Q}_b$.

from which we obtain

$$\delta^{\text{large}} = 1 - \sqrt{\frac{1}{2}(1+p) + \frac{A_e}{A_{UBZ}} + d^2} \quad (2)$$

on substituting \mathbf{Q}_a and \mathbf{Q}_b and rearranging terms. Here δ^{large} refers to the average $\frac{1}{2}(\delta_a^{\text{large}} + \delta_b^{\text{large}})$ while d refers to half the difference $\frac{1}{2}(\delta_a^{\text{large}} - \delta_b^{\text{large}})$. Since $d^2 < 10^{-4}$, this term can mostly be neglected. The functional form of Equation (2) is identical to that obtained by way of a full numerical calculation in Ref. 25 – where it was the period $\lambda = 1/\delta^{\text{large}}$ of the density-wave that was being plotted. The reconstructed Fermi surface in Fig. 3b has the same diamond-shaped electron pocket (indicated in pink) as discussed in several earlier biaxial reconstruction scenarios.^{24–32}

C. Small Fermi surface and biaxial order

On considering biaxial density-wave ordering starting from a small Fermi surface of the form shown in Fig. 1b, the doped holes are generally thought to be bounded by the antiferromagnetic Brillouin zone^{5–8}. We must therefore sum the areas within the antiferromagnetic Brillouin zone of area $A_{ABZ} = \frac{1}{2}A_{UBZ}$ (see Fig. 4a) and neglect the regions outside antiferromagnetic Brillouin zone shaded in grey. The area $A_p = \frac{p}{2}A_{UBZ}$ of the Brillouin zone occupied by holes (indicated in white) is now significantly smaller than before.

The effect of \mathbf{Q}_b is once again to remove electrons from the unreconstructed Fermi surface occupying a total area $\mathbf{K}_a \cdot \mathbf{Q}_b$ (indicated in yellow). This time, the second vector \mathbf{Q}_a removes electrons occupying a remaining area of $\mathbf{Q}_a(\mathbf{K}_b - 2\mathbf{Q}_b)$ (indicated in green). On equating all of these areas to $\frac{1}{2}A_{ABZ}$ in Fig. 3b we arrive at

$$\mathbf{K}_a \cdot \mathbf{Q}_b + \mathbf{Q}_a(\mathbf{K}_b - 2\mathbf{Q}_b) + A_e + A_p = \frac{1}{2}A_{UBZ}$$

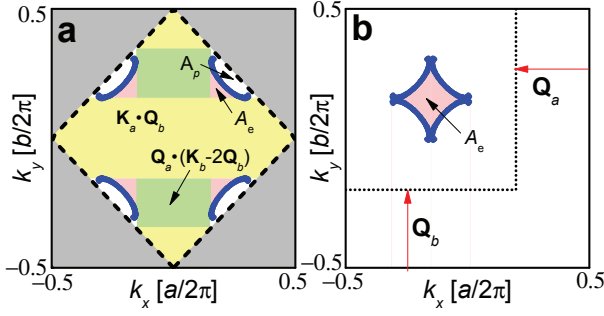


FIG. 4: (a), The small Fermi surface within the antiferromagnetic Brillouin zone with the different area contributions shaded. Grey indicates the regions outside the antiferromagnetic Brillouin zone. (b), Schematic showing the reconstructed electron pocket after translation of parts of the unreconstructed Fermi surface by \mathbf{Q}_a , \mathbf{Q}_b and $\mathbf{Q}_a + \mathbf{Q}_b$.

from which we obtain

$$\delta^{\text{small}} = \frac{1}{2} - \sqrt{\frac{1}{2} \left(\frac{p}{2} + \frac{A_e}{A_{\text{UBZ}}} \right) + d^2} \quad (3)$$

on substituting \mathbf{Q}_a and \mathbf{Q}_b and rearranging terms. Here, similar to what we have for the large Fermi surface, $\delta^{\text{small}} = \frac{1}{2}(\delta_a^{\text{small}} + \delta_b^{\text{small}})$ while $d = \frac{1}{2}(\delta_a^{\text{small}} - \delta_b^{\text{small}})$. The reconstructed Fermi surface in Fig. 4b continues to have the same diamond-shaped electron pocket (indicated in pink) as discussed in several earlier publications.^{24–32}

Equation (3) can be reconciled with the doping-dependent charge-density-wave vector obtained by Atkinson *et al.*⁵³. In this case, there are two diamond-shaped pockets that result from the charge-density-wave vectors not connecting with the antiferromagnetic Brillouin zone boundary, in which case A_e must correspond to the sum of both electron pocket areas.

D. Generalized Fermi surface considerations

In the case of more generalized forms for the large unreconstructed hole Fermi surface in the cuprates, the outcome will depend on the strength of the charge-density wave coupling. In the weak coupling limit, imperfect nesting produces additional small sections of Fermi surface. Examples of such pockets are described for the case of biaxial charge-density wave ordering in Refs.^{24,29} The areas of these sections of Fermi surface must be respectively added to or subtracted from A_e , depending on whether they contain electrons or holes. Hole pockets like those discussed in Ref.²⁹ cannot contribute to δ^{small} , however, as these would lie mostly outside of the antiferromagnetic Brillouin zone.

Small additional sections of Fermi surface are less likely to occur as the strength of the charge-density wave coupling is increased. As the coupling is progressively increased, the Fermi surface will eventually consist of a

single reconstructed electron pocket.²⁴ At this point one can then draw shaded regions with areas equal to those in Figs. 2b and 3a that add up to A_{UBZ} . The shapes are nevertheless likely to become more irregular. There are two reasons why Equations (1) and (2) continue to be valid upon increasing the charge-density wave coupling. The first is that the chemical potential always adjusts itself to maintain the area A_{1+p} of the Brillouin zone occupied by holes at a value compatible with the hole doping. The area A_{1+p} is therefore invariant under an increase in the coupling strength. The second reason is that each cycle of a spin- or charge-density wave state always contains precisely an even number of electrons or holes and increments the phase by 2π . The number of electrons removed from the Fermi surface by a density-wave state, and the area that they occupy within the Brillouin zone, is therefore also independent of the strength of coupling. The pocket area A_e , meanwhile, is constrained by Onsager's relation $A_e = 2\pi e F_e / \hbar$, where F_e is the measured quantum oscillation frequency.

Bilayer coupling will have different effects on the doping dependence of δ , depending on its strength compared to the strength of the spin- or charge-density wave coupling, or depending on whether the density-wave connects bands of the same or opposite parity. If the bilayer coupling is much weaker than the density-wave coupling, or if the density-wave connects bilayer-split bands of opposite parity,³² then there will continue to be single values of δ^{large} and δ^{small} . Briffa *et al.*³² have shown that in the case where the density-wave connects bands of opposite parity, two degenerate reconstructed Fermi surfaces are obtained that are related to each other by way of a 90° rotation. If, on the other hand, bilayer coupling is large and the density-wave connects bilayer-split bands of like parity,⁴⁵ one will then find that δ , A_e and A_{1+p} can each have different values for the bonding and antibonding bands. Recent x-ray scattering studies indicate a broken mirror plane orthogonal to the c axis centered on the bilayer in $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$,^{23,46} which supports a scenario in which density-wave connects bands of opposite parity.³²

III. COMPARISON WITH EXPERIMENT

Figure 5 shows the doping-dependence of δ_b^{open} , δ^{large} and δ^{small} calculated using Equations (1), (2) and (3), respectively, neglecting d^2 . In Fig. 5a we compare the lengths of the charge-density wave ordering vectors δ_a and δ_b obtained in x-ray scattering experiments^{19,20} in $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ with those calculated using the ratio $\frac{A_e}{A_{\text{UBZ}}}$ obtained from magnetic quantum oscillation experiments (assuming Onsager's relation).⁴⁷ We assume a single pocket per CuO_2 plane³² and approximate the doping-dependent quantum oscillation frequency in Ref.⁴⁷ with a linear fit, from which we obtain $F_e \approx (399 + 1288 p)$ T. In Fig. 5b we compare the length of the charge-density wave ordering vector δ_a obtained in an x-ray scattering

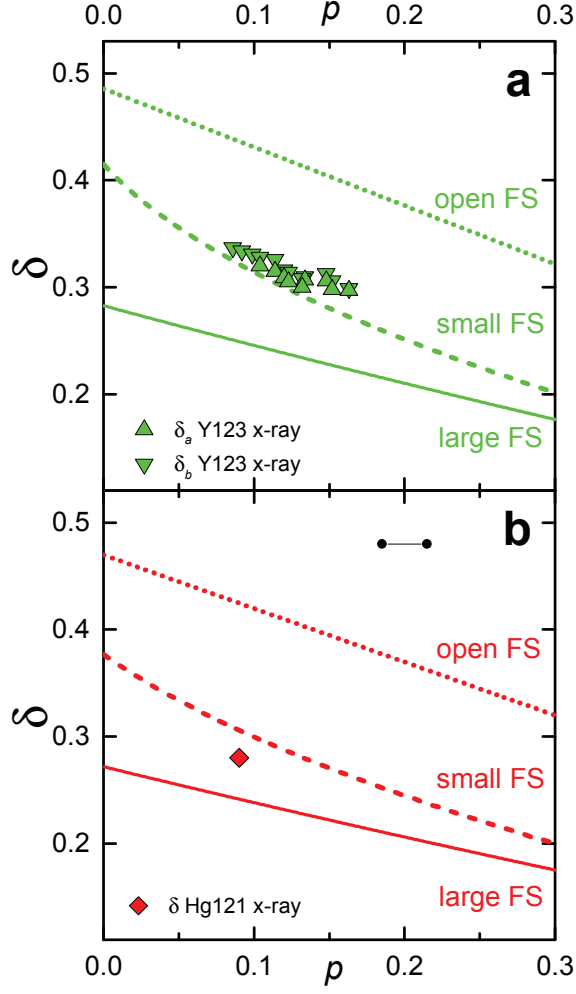


FIG. 5: (a), A comparison of δ calculated according to the three different open (dotted line), large (solid line) and small (dashed line) Fermi surface models [using Equations (1), (2) and (3)] with experimental $\delta_{a,b}$ values obtained using x-ray scattering, as indicated. Data are shown for YBa₂Cu₃O_{6+x} (Y123)^{19,20} in (a) and HgBa₂CuO_{4+x} (Hg121)²¹ in (b). The horizontal black line separating two dots shows the possible magnitude of the uncertainty in doping between YBa₂Cu₃O_{6+x} and HgBa₂CuO_{4+x}, which may be typical in the cuprates.

experiment²¹ in HgBa₂CuO_{4+x}, assuming that $\delta_b = \delta_b$ in the tetragonal crystal structure, with those calculated using the ratio $\frac{A_e}{A_{UBZ}}$ obtained from magnetic quantum oscillation experiments.³⁶ In this case $F_e \approx 840$ T is the quantum oscillation frequency measured at a single value of the hole doping.

IV. DISCUSSION

It is clear from Fig. 5 that the experimentally observed values of the charge-density wave ordering vector lengths δ_a (and δ_b in the case of YBa₂Cu₃O_{6+x}), are much

shorter than those δ^{open} expected for a nematically-deformed Fermi surface accompanied by the formation of a unidirectional charge-density wave producing a single reconstructed Fermi surface pocket. The observed values of the charge-density wave ordering vector lengths are also found to be much longer than those δ^{large} expected for biaxial order producing a single reconstructed Fermi surface pocket starting from a large unreconstructed Fermi surface comprising $1 + p$ hole carriers, as predicted by band structure calculations. Only by considering a small starting Fermi surface comprising p carriers, do we find the predicted ordering vector lengths δ^{small} to be consistent with $\delta_{a,b}$ both at a quantitative level and in the overall form of its doping dependence.

Some degree of discrepancy between $\delta_{a,b}$ and δ^{small} could potentially originate from assumptions that are made to evaluate the chemical hole doping, or to the presence of additional, as yet unobserved, small Fermi surface pockets. In YBa₂Cu₃O_{6+x}, for example, the hole doping is estimated by comparing the doping dependence of the rescaled superconducting transition temperature T_c with that of La_xSr_{2-x}CuO₄.⁴⁸ In HgBa₂CuO_{4+x}, meanwhile, the maximum quantum oscillation amplitude and plateaux in T_c versus p are found to occur near $p \approx 0.09$ ⁴¹ rather than $p \approx 0.12$ in YBa₂Cu₃O_{6+x}. Closer agreement with δ^{small} would be obtained in Fig. 5b were p estimated using the same method as used for YBa₂Cu₃O_{6+x}.⁴⁸

The form of the electronic dispersion at the antiferromagnetic Brillouin zone boundary is unique for each model of the small starting Fermi surface.⁵⁻⁸ However, since it is the states close to the antiferromagnetic Brillouin zone boundary that become gapped by the charge-density wave (see Fig. 6), the unique differences in their dispersions are essentially lost once Fermi surface reconstruction takes place. The primary role of the Coulomb repulsion in all of these models is therefore only to provide a mechanism for the opening of a large gap in the in the antinodal region of the Brillouin zone.

The close correspondence of $\delta_{a,b}$ with δ^{small} expected for a small Fermi surface implies that the experimental values of $\delta_{a,b}$ and A_e can be used to obtain the number of holes contained within the Fermi surface. On rearranging the terms in Equation (3) and using $n_h = 2A_p/A_{UBZ}$, we obtain

$$n_h = 4 \left[\left(\frac{1}{2} - \delta \right)^2 - d^2 - \frac{A_e}{2A_{UBZ}} \right]. \quad (4)$$

In Fig. 1c, we compare the experimental estimates of n_h against those $n_h = p$ and $n_h = 1 + p$ expected for the small and large Fermi surface, respectively. A continuation of the linear trend $n_h = p$ previously obtained for very low hole dopings $p < 0.08$ ¹² is suggested, followed by a sharp jump by one hole per CuO₂ plane near optimal doping to arrive at $n_h = 1 + p$.

Measurements of the Hall coefficient R_H have suggested an increase in n_h near optimal dopings,⁹ although they have also suggested the crossover between $n_h = p$ and $n_h = 1 + p$ to occur over an extended range of dop-

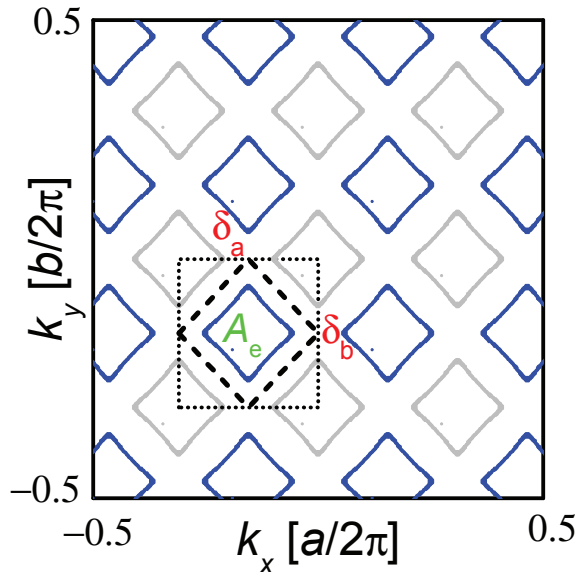


FIG. 6: Schematic reconstructed Fermi surface in the repeated Brillouin zone representation, with the electron pocket indicated in blue and the folded antiferromagnetic Brillouin zone boundary indicated by a dashed line. In all reconstruction scenarios involving the small starting Fermi surface, the states along the folded antiferromagnetic Brillouin zone become gapped by the charge-density wave order. If the wave vector \mathbf{Q}_{AFM} , in addition to \mathbf{Q}_a and \mathbf{Q}_b , is involved in reconstructing the Fermi surface, then the dashed line becomes the true reconstructed Brillouin zone boundary and additional instances of the reconstructed electron pocket will appear (depicted in grey).

ings $0.15 < p < 0.20$. Several factors, including changes curvature around the Fermi surface and anisotropic scattering rates,^{30,50–52} cause R_H no longer to be directly related to the number of carriers or the sign of the carriers contained within the Fermi surface once $\omega_c \tau \lesssim 1$, where ω_c is the cyclotron frequency and τ is the scattering time. This situation is more likely to apply near optimal doping owing to the increase in τ^{-1} .

V. CONCLUSION

Having considered a large starting Fermi surface comprising $n_h = 1 + p$ hole carriers, as predicted by band structure calculations, and a small starting Fermi surface comprising $n_h = p$ carriers, as expected in the presence of antiferromagnetic correlations, we find the small starting Fermi surface to show a close correspondence with the lengths of the wave vectors $\delta_{a,b}$ obtained from x-ray diffraction experiments within the underdoped regime over a broad range of hole dopings. The reconstructed Fermi surface seen in magnetic quantum oscillation and the ‘Fermi arcs’ seen in angle-resolved photoemission spectroscopy⁴⁹ measurements must therefore originate from the same small starting Fermi surface. Our findings imply that quantum oscillation frequency and charge-density wave vectors can be used to provide an accurate means for estimating the number of holes contained within the Fermi surface over the majority of the pseudogap regime in the low temperature limit.

A small starting Fermi surface consisting of four hole pockets (e.g. Fig. 1b) is expected to be one of the consequences of the on-site Coulomb repulsion continuing to remain dominant over low energy excitations when holes are doped into the Mott insulator.^{5–8} It raises the possibility of an interesting scenario in which the Coulomb repulsion remains the dominant energy scale throughout the entire pseudogap regime and plays an important role in the quantum critical behavior close to optimal doping.⁴⁷

VI. ACKNOWLEDGEMENTS

This work is supported by the US Department of Energy BES “Science at 100 T” grant no. LANLF100, the National Science Foundation and the State of Florida.

¹ E. Dagotto, Rev. Mod. Phys. **66**, 763 (1994).

² M. Imada, A. Fujimori, Y. Tokura, Rev. Mod. Phys. **70**, 1039 (1998).

³ T. Timusk, B. Statt, Rep. Prog. Phys. **62**, 61 (1999).

⁴ O. K. Andersen *et al.*, Phys. Chem. Solids **56**, 1573 (1995).

⁵ S. Chakravarty *et al.*, Phys. Rev. B **63**, 094503 (2001).

⁶ P. A. Lee, N. Nagaosa, X. G. Wen, Rev. Mod. Phys. **78**, 17 (2006).

⁷ T. M. Rice, K.-Y. Yang, F. C. Zhang, Rep. Prog. Phys. **75**, 016502 (2012).

⁸ Y. Qi, S. Sachdev, Phys. Rev. B **81**, 115129 (2010).

⁹ S. Badoux, W. Tabis, F. Lalibert, G. Grissonnache, B. Vignolle, D. Vignolles, J. Béard, D. A. Bonn, W. N. Hardy, R. Liang, N. Doiron-Leyraud, L. Taillefer, C. Proust, Na-

ture **531**, 210 (2016).

¹⁰ B. Vignolle, A. Carrington, R. A. Cooper, M. M. French, A. P. Mackenzie, C. Jaudet, D. Vignolles, C. Proust, N. E. Hussey, Nature **455**, 952 (2008).

¹¹ N. E. Hussey *et al.*, Nature **425**, 814 (2003). A coherent three-dimensional Fermi surface in a high-transition-temperature superconductor

¹² K. Segawa, Y. Ando, Phys. Rev. B **69**, 104521 (2004).

¹³ F. F. Balakirev, Phys. Rev. Lett. **102**, 017004 (2009).

¹⁴ D. LeBoeuf *et al.*, Nature **450**, 533 (2007).

¹⁵ N. Doiron-Leyraud, S. Lepault, O. Cyr-Choiniere, B. Vignolle, G. Grissonnache, F. Lalibert, J. Chang, N. Barisic, M. K. Chan, L. Ji, X. Zhao, Y. Li, M. Greven, C. Proust, Phys. Rev. X **3**, 021019 (2013).

- ¹⁶ T. Wu *et al.*, Nature **477**, 191 (2011).
- ¹⁷ G. Ghiringhelli *et al.*, Science **337**, 821 (2012).
- ¹⁸ J. Chang *et al.*, Nature Phys. **8**, 871 (2012).
- ¹⁹ E. Blackburn *et al.*, Phys. Rev. Lett. **110**, 137004 (2013).
- ²⁰ S. Blanco-Canosa *et al.*, Phys. Rev. Lett. **110**, 187001 (2013).
- ²¹ W. Tabis, Y. Li, M. Le Tacon, L. Braicovich, A. Kreyssig, M. Minola, G. Dellea, E. Weschke, M. J. Veit, M. Ramazanoglu, A. I. Goldman, T. Schmitt, G. Ghiringhelli, N. Barisic, M. K. Chan, C. J. Dorow, X. Zhao, B. Keimer, M. Greven, Nature Commun. **5**, 5875 (2014).
- ²² S. Gerber, H. Jang, H. Nojiri, S. Matsuzawa, H. Yasumura, D. A. Bonn, R. Liang, W. N. Hardy, Z. Islam, A. Mehta, S. Song, M. Sikorski, D. Stefanescu, Y. Feng, S. A. Kivelson, T. P. Devereaux, Z.-X. Shen, C.-C. Kao, W.-S. Lee, D. Zhu, J.-S. Lee, Science: DOI: 10.1126/science.aac6257.
- ²³ J. Chang, E. Blackburn, O. Ivashko, A. T. Holmes, N. B. Christensen, M. Hcker, Ruixing Liang, D. A. Bonn, W. N. Hardy, U. Rtt, M. v. Zimmermann, E. M. Forgan, S. M. Hayden, arXiv:1511.06092.
- ²⁴ N. Harrison, S. E. Sebastian, Phys. Rev. Lett. **106**, 226402 (2011).
- ²⁵ N. Harrison, Phys. Rev. Lett. **107**, 186408 (2011).
- ²⁶ S. E. Sebastian *et al.*, Phys. Rev. Lett. **108**, 196403 (2012).
- ²⁷ S. E. Sebastian, N. Harrison, G. G. Lonzarich, Rep. Prog. Phys. **75**, 102501 (2012).
- ²⁸ A. V. Maharaj, P. Hosur, S. Raghu, Phys. Rev. B **90**, 125108 (2014).
- ²⁹ A. Allais, D. Chowdhury, S. Sachdev, Nature Commun. DOI: 10.1038/ncomms6771 (2014).
- ³⁰ N. Harrison, S. E. Sebastian, Phys. Rev. B **92**, 224505 (2015).
- ³¹ P. Robinson, N. E. Hussey, Phys. Rev. B **92**, 220501 (2015).
- ³² A. Briffa, E. Blackburn, S.M. Hayden, E.A. Yelland, M.W. Long, E. M. Forgan, Phys. Rev. B **93**, 094502 (2016).
- ³³ N. Doiron-Leyraud *et al.*, Nature **447**, 565 (2007).
- ³⁴ E. A. Yelland *et al.*, Phys. Rev. Lett. **100**, 047003 (2008).
- ³⁵ A. F. Bangura *et al.*, Phys. Rev. Lett. **100**, 047004 (2008).
- ³⁶ N. Barišić *et al.*, preprint arXiv:1310.1414 (2013).
- ³⁷ S. C. Riggs, O. Vafek, J. B. Kemper, J. B. Betts, A. Migliori, W. N. Hardy, R. X. Liang, D. A. Bonn, G. S. Boebinger, Nature Phys. **7**, 332 (2011).
- ³⁸ C. Marcenat *et al.*, Nature Commun. **6**, 7927 (2015).
- ³⁹ W. D. Wise *et al.*, Nature Phys. **4**, 696 (2008).
- ⁴⁰ B. Comin *et al.*, preprint arXiv:1312.1343 (2013).
- ⁴¹ M. Chan *et al.* (unpublished, 2016).
- ⁴² Y.-T. Hsu *et al.* (unpublished, 2016).
- ⁴³ P. M. Chaikin, J. Phys. I France **6**, 1875 (1996).
- ⁴⁴ H. Yao, D.-H. Lee, S. Kivelson, Phys. Rev. B **84**, 012507 (2011).
- ⁴⁵ N. Harrison, S. E. Sebastian, N. J. Phys. **14**, 095023 (2012).
- ⁴⁶ E. M. Forgan *et al.*, Nature Commun. **6**, 10064 (2015).
- ⁴⁷ B. J. Ramshaw *et al.*, Science **348**, 317 (2015).
- ⁴⁸ R. Liang, D. A. Bonn, W. N. Hardy, Phys. Rev. B **73**, 180505 (2006).
- ⁴⁹ M. A. Hossain *et al.*, Nature Phys. **4**, 527 (2008).
- ⁵⁰ S. Caprara *et al.*, arXiv:1604.07852 (2016).
- ⁵¹ J. Lin, A. J. Millis, Phys. Rev. B **72**, 214506 (2005).
- ⁵² P. Robinson, N. E. Hussey, Phys. Rev. B **92**, 220501 (2015).
- ⁵³ W. A. Atkinson, A. P. Kampf, S. Bulut, New J. Phys. **17**, 013025 (2015).
- ⁵⁴ V. Hinkov, D. Haug, B. Fauque, P. Bourges, Y. Sidis, A. Ivanov, C. Bernhard, C. T. Lin, B. Keimer, Science **319**, 597 (2008).
- ⁵⁵ P. C. Dai, H. A. Mook, R. D. Hunt, F. Dogan, Phys. Rev. B **63**, 054525 (2001).